

## COMPLEMENTARY SILICON POWER TRANSISTORS

...designed for various specific and general purpose application such as; output and driver stages of amplifiers operating at frequencies from DC to greater than 1.0MHz series, shunt and switching regulators; low and high frequency inverters/converters and many others.

### FEATURES:

- \* Very Low Collector Saturation Voltage
- \* Excellent Linearity
- \* Fast Switching
- \* PNP Values are Negative, Observe Proper Polarity.

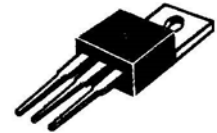
**NPN**  
**D44C**  
**Series**

**PNP**  
**D45C**  
**Series**

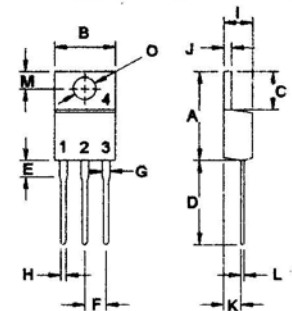
**4 AMPERE**  
**COMPLEMENTARY SILICON**  
**POWER TRANSISTORS**  
**30-80 VOLTS**  
**30 WATTS**

### MAXIMUM RATINGS

Characteristic	Symbol	D44C1,2,3 D45C1,2,3	D44C4,5,6 D45C4,5,6	D44C7,8,9 D45C7,8,9	D44C10,11,12 D45C10,11,12	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	45	60	80	V
Collector-Emitter Voltage	$V_{CES}$	40	55	70	90	V
Emitter-Base Voltage	$V_{EBO}$	5.0				V
Collector Current - Continuous Peak	$I_C$ $I_{CM}$	4.0 6.0				A
Base Current	$I_B$	1.0				A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	30 0.24				W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	-55 to +150				$^\circ\text{C}$



**TO-220**

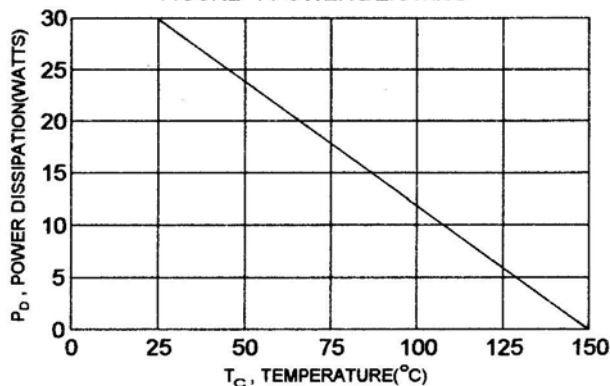


PIN 1. BASE  
2. COLLECTOR  
3. EMITTER  
4. COLLECTOR(CASE)

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta JC}$	4.2	$^\circ\text{C/W}$

**FIGURE -1 POWER DERATING**



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

# D44C Series NPN / D45C Series PNP

## ELECTRICAL CHARACTERISTICS ( $T_c = 25^\circ\text{C}$ unless otherwise noted )

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Base Cutoff Current ( $V_{CE} = \text{Rated } V_{CES}$ )	$I_{CES}$		10	$\mu\text{A}$
Emitter-Base Cutoff Current ( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$		100	$\mu\text{A}$

### ON CHARACTERISTICS(1)

DC Current Gain ( $I_C = 0.2\text{ A}$ , $V_{CE} = 1.0\text{ V}$ )	D44C3,6,9,12/ D45C3,6,9,12 D44C2,5,8,11 D45C2,5,8,11	$h_{FE}$	40 100 40	120 220 120	
( $I_C = 1.0\text{ A}$ , $V_{CE} = 1.0\text{ V}$ )	D44C1,4,7,10/D45C1,4,7,10 D44C1,4,7,10/D45C1,4,7,10 D45C2,5,8,11		25 10 20		
( $I_C = 2.0\text{ A}$ , $V_{CE} = 1.0\text{ V}$ )	D44C3,6,9,12/ D45C3,6,9,12 D44C2,5,8,11		20 20		
Collector-Emitter Saturation Voltage ( $I_C = 1.0\text{ A}$ , $I_B = 50\text{ mA}$ )	D44C2,3,5,6,8,9,11,12 D45C2,3,5,6,8,9,11,12	$V_{CE(sat)}$		0.5 0.5	V
( $I_C = 1.0\text{ A}$ , $I_B = 100\text{ mA}$ )	D44C1,4,7,10/D45C1,4,7,10			0.5	
Base-Emitter Saturation Voltage ( $I_C = 1.0\text{ A}$ , $I_B = 100\text{ mA}$ )	All Devices	$V_{BE(sat)}$		1.3	V

### DYAMIC CHARATERISTICS

Current-Gain Bandwidth Product (2) ( $I_C = 20\text{ mA}$ , $V_{CE} = 4.0\text{ V}$ , $f = 1.0\text{ MHz}$ )	D44C Series D45C Series	$f_T$	50(typ) 40(typ)		MHz
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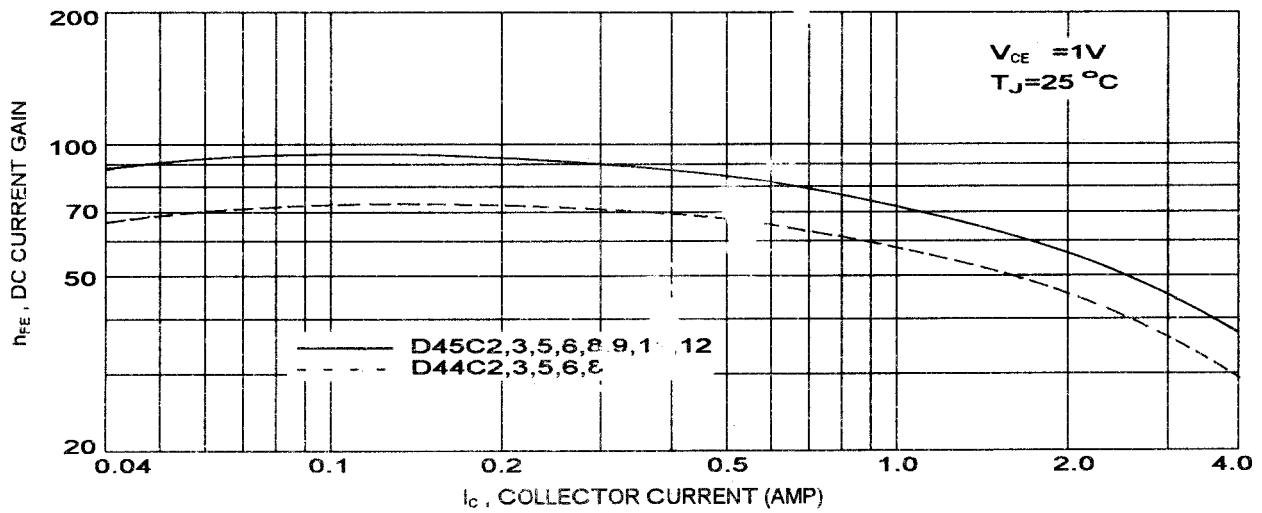
### SWITCHING CHARATERISTICS

Rise Time	$V_{CC} = 20\text{ V}$	D44C Series D45C Series	$t_r$		0.3 0.2	$\mu\text{s}$
Storage Time	$I_C = 1.0\text{ A}$ ,	D44C Series D45C Series	$t_s$		0.7 0.6	$\mu\text{s}$
Fall Time	$I_{B1} = -I_{B2} = 100\text{ mA}$	D44C Series D45C Series	$t_f$		0.4 0.3	$\mu\text{s}$

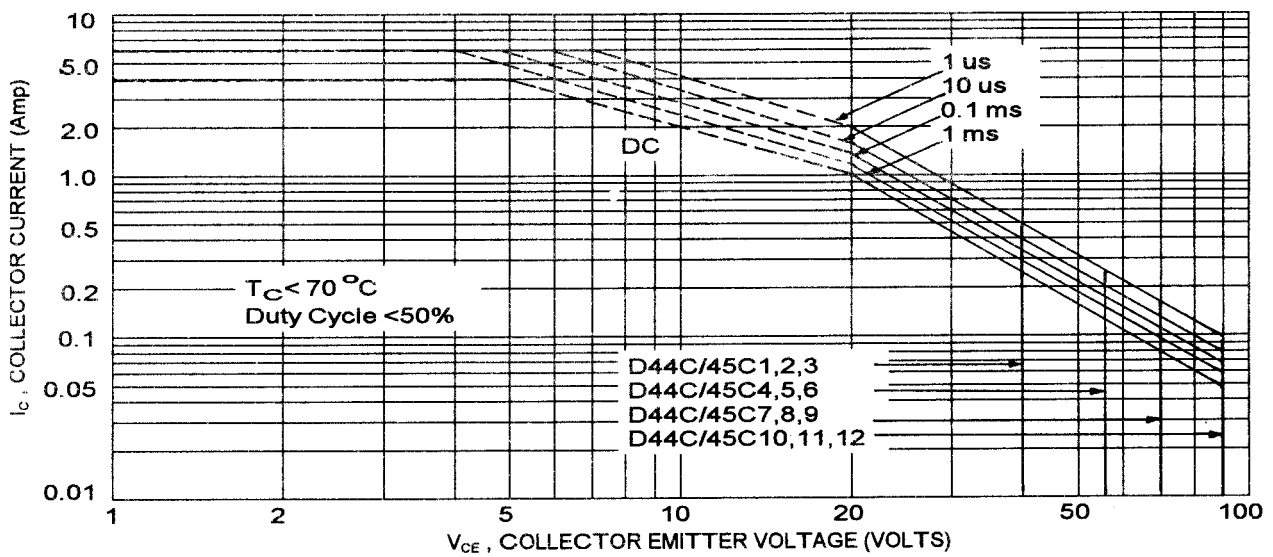
(1) Pulse Test: Pulse width = 300  $\mu\text{s}$  , Duty Cycle  $\leq 2.0\%$

(2)  $f_T = |h_{fe}| \cdot f_{test}$

DC CURRENT GAIN



FORWARD BIAS SAFE OPERATING AREA



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